TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

2SC2500

Strobe Flash Applications Medium-Power Amplifier Applications

• High DC current gain and excellent hFE linearity

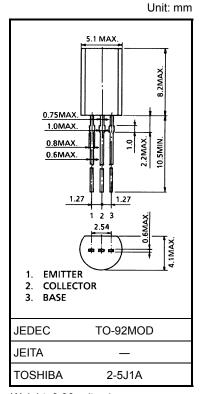
: $h_{FE}(1) = 140 \text{ to } 600 \text{ (V}_{CE} = 1 \text{ V, I}_{C} = 0.5 \text{ A})$

 $: h_{FE} (2) = 70 \text{ (min)}, 200 \text{ (typ.)}, (V_{CE} = 1 \text{ V}, I_{C} = 2 \text{ A})$

• Low saturation voltage: V_{CE} (sat) = 0.5 V (max) (I_{C} = 2 A, I_{B} = 50 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	30	V	
Collector-emitter voltage		V _{CES}	30	V	
		V _{CEO}	10		
Emitter-base voltage		V_{EBO}	6	V	
Collector current	DC	Ic	2	А	
	Pulsed (Note 1)	I _{CP}	5		
Base current		ΙΒ	0.5	Α	
Collector power dissipation		PC	900	mW	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.36 g (typ.)

Note 1: Pulse test: Pulse width = 10 ms (max), duty cycle = 30% (max)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

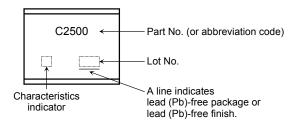
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

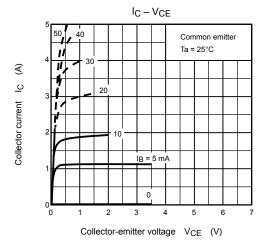
Electrical Characteristics (Ta = 25°C)

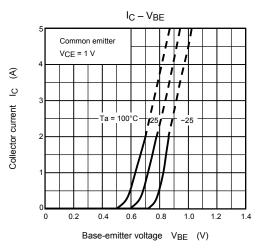
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 30 V, I _E = 0	_	_	100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 6 V, I _C = 0	_	_	100	nA
Collector-emitter breakdown voltage	V_{CEO}	I _C = 10 mA, I _B = 0	10	_	_	V
Emitter-base breakdown voltage	V _{EBO}	I _C = 1 mA, I _C = 0	6	_	_	V
DC current gain	h _{FE (1)} (Note 3)	V _{CE} = 1 V, I _C = 0.5 A	140	_	600	
	h _{FE (2)}	V _{CE} = 1 V, I _C = 2 A	70	200	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 2 A, I _B = 50 mA	_	0.2	0.5	V
Base-emitter voltage	V _{BE}	V _{CE} = 1 V, I _C = 2 A	_	0.86	1.5	V
Transition frequency	f _T	V _{CE} = 1 V, I _C = 0.5 A	_	150	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	27	_	pF

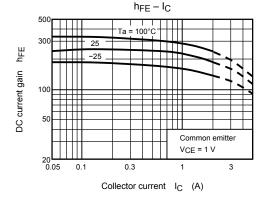
Note 3: $h_{FE\ (1)}$ classification A: 140 to 240, B: 200 to 330, C: 300 to 450, D: 420 to 600

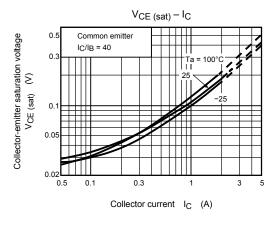
Marking

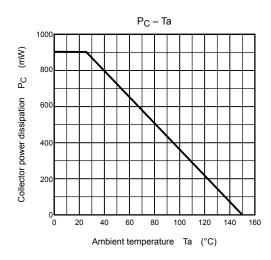


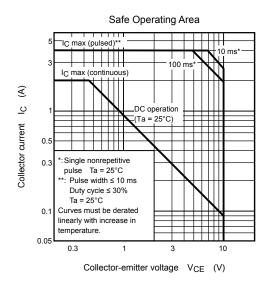












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